Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-291-6407

Inclosure Material:
Metal and glass
Overall Length:
Between 0.155 inches and 0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.190 inches and 0.210 inches
Features Provided:
Electrostatic sensitive
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 breakdown voltage, dc and 475.0 breakdown voltage, dc
Current Rating Per Characteristic:
5.00 milliamperes source cutoff current preset
Maximum Operating Tempurature Per Measurement Point:
70.0 degrees celsius ambient air
Special Features:
Field force effect type: electrostatic charge
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0